

Supplementary information (ESI)

A facile room temperature chemical transformation approach for binder-free thin film formation of Ag₂Te and lithiation/delithiation chemistry of the film

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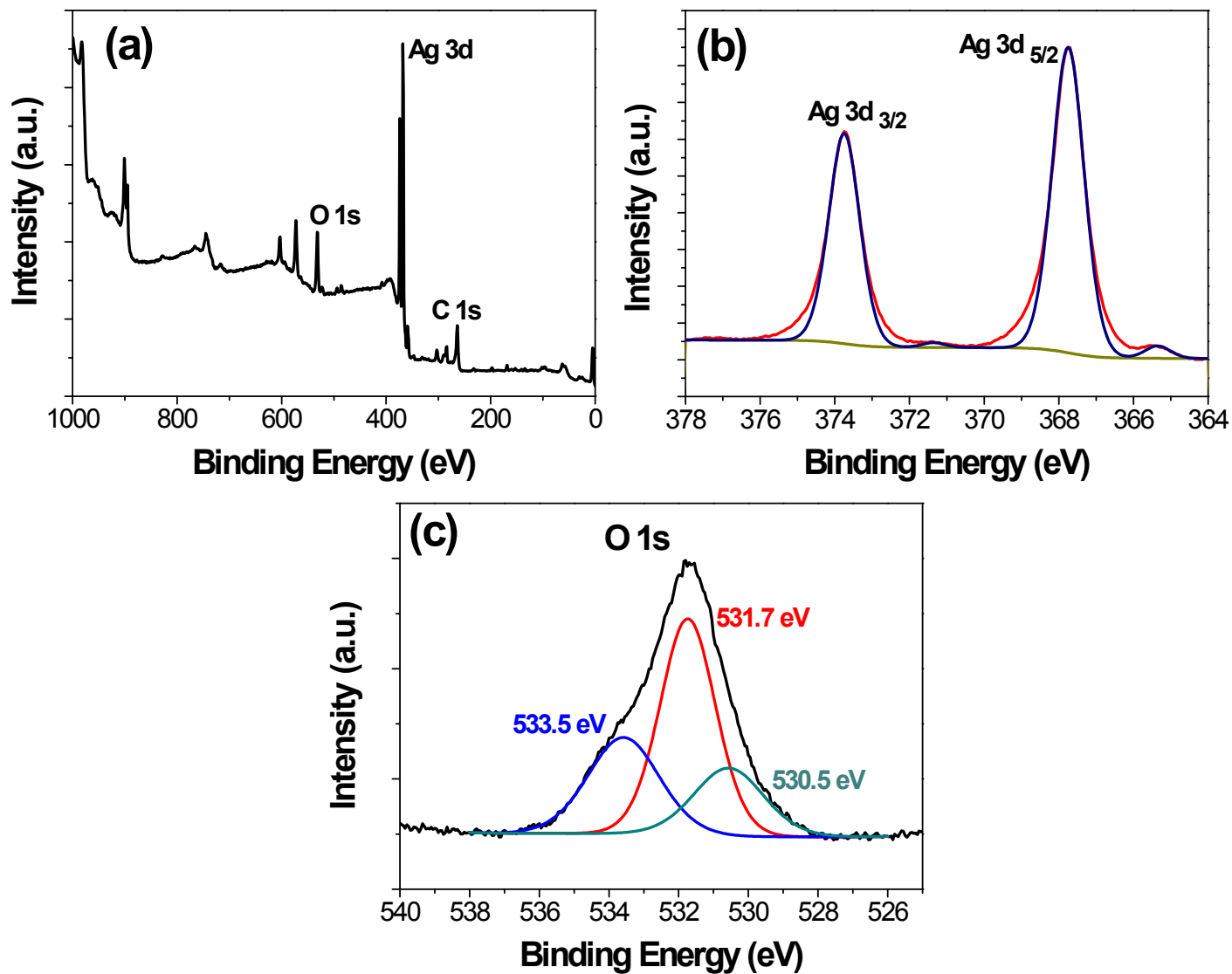


Fig. S1. XPS spectra of Ag/Ag_xO film. (a) Survey spectrum, (b) Ag 3d core level spectrum, and (c) O 1s core level spectrum.

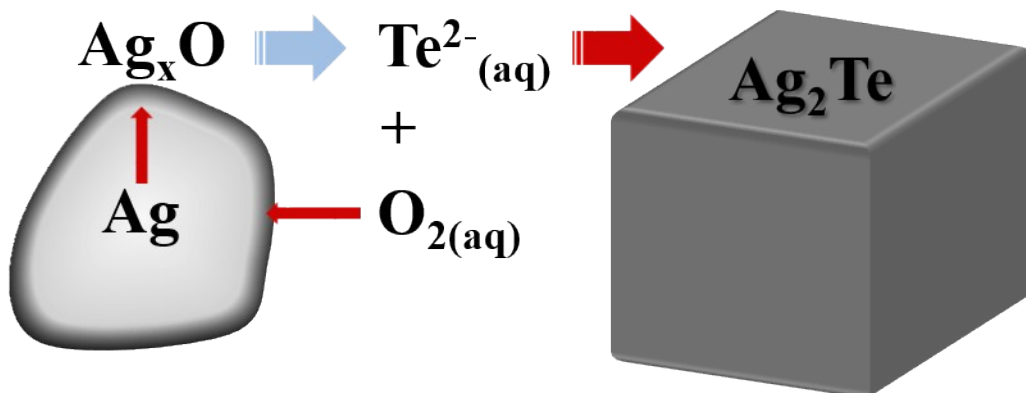


Fig. S2. Schematic diagram showing the surface oxidation of Ag particles followed by chemical transformation into Ag_2Te in presence of aqueous Te-precursor solution at room temperature.

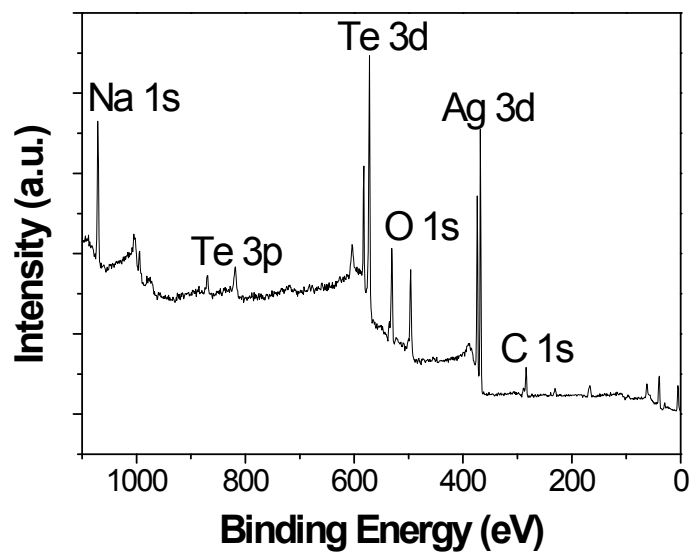
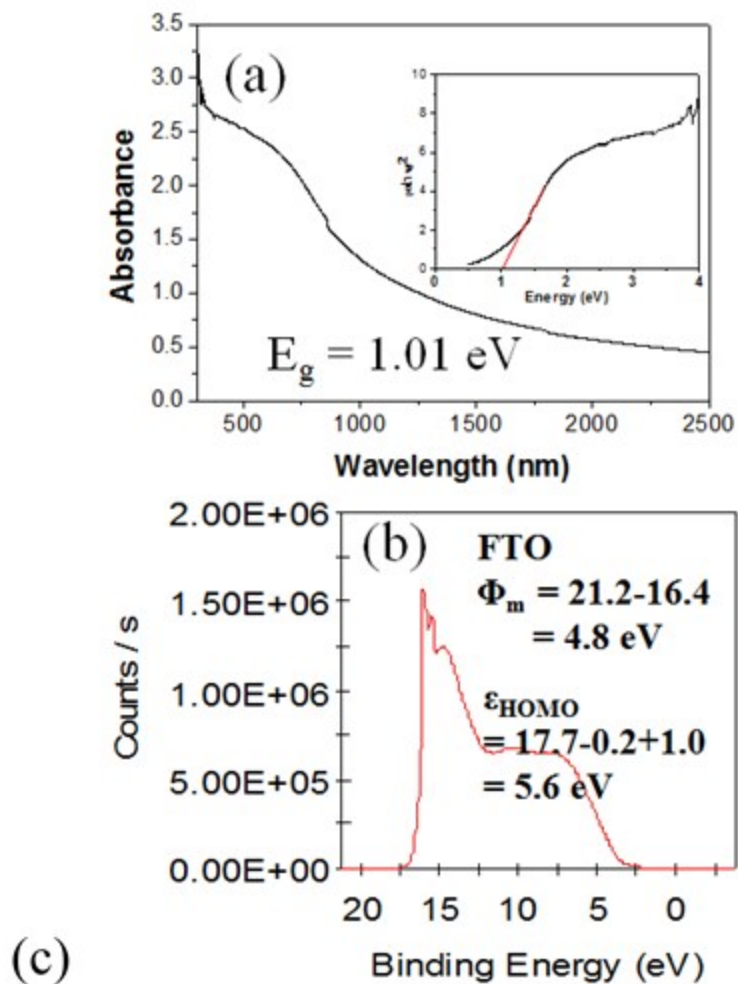


Fig. S3. XPS survey spectrum of chemically transformed Ag_2Te film. The Na signal at 1071.12 eV is attributed to residual NaOH.



RESULT			
Bulk concentration =	3.097E+17 [J/Cm^3]	Sheet Concentration =	6.195E+13 [J/Cm^2]
Mobility =	4.779E+1 [Cm^2/Vs]	Conductivity =	2.371E+0 [$1/\Omega \text{ Cm}$]
Resistivity =	4.217E-1 [$\Omega \text{ Cm}$]	Average Hall Coefficient =	2.015E+1 [m^2/C]
A-C Cross Hall Coefficient =	1.745E+1 [m^2/C]	B-D Cross Hall Coefficient =	2.286E+1 [m^2/C]
Magneto-Resistance =	1.070E+1 [Ω]	Ratio of Vertical / Horizontal =	2.579E-1

Fig. S4. (a) UV-vis absorption spectrum of Ag_2Te film and inset shows the Tauc plot for estimation of optical gap. (b) UPS spectrum for estimation of valence band edge position of Ag_2Te film. (c) Various parameters obtained from Hall measurement of the Ag_2Te film.

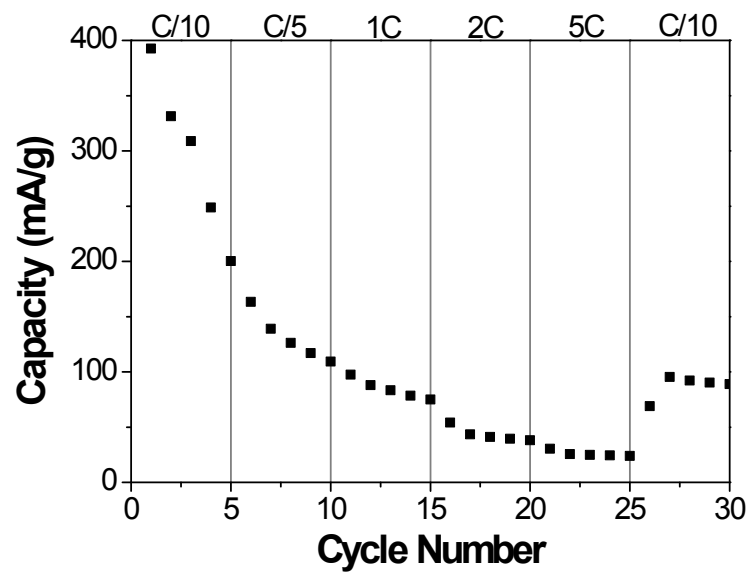


Fig. S5 Charge–discharge curves of the Li/LiPF₆/Ag₂Te battery at various current densities.